NSN 5961-01-521-9467

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-521-9467 **Inclosure Material:** Plastic **End Application:** Helicopter, lamps mark iii, sh-60b Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 regulator voltage, dc **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector megawatts **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: